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Tricks of Strain and Treats of Emergent Phases: Unraveling Altermagnetism and Polar Metallic States in Epitaxial RuO₂ Films

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RuO₂, a rutile 4d-transition metal oxide, exhibits a unique crystal structure with both edge- and corner-sharing octahedra. This intrinsic anisotropy, when combined with strain engineering, provides a powerful avenue for tuning anisotropic electronic and optical properties. However, from a synthesis perspective, challenges such as variable Ru valence states, Ru/O stoichiometry control, anisotropic strain states, and structural defects can make it difficult to distinguish intrinsic properties from extrinsic effects in RuO₂ thin films—a classic trick in the pursuit of novel functionalities in quantum materials.

In this talk, I will highlight our group's efforts in overcoming these synthesis challenges while demonstrating metallicity in epitaxial RuO₂ films down to the unit cell scale. Through a combination of advanced X-ray scattering, X-ray absorption spectroscopy, transmission electron microscopy, temperature-dependent transport, magneto-optical measurements, and density functional theory (DFT) calculations, we uncover robust magnetism in epitaxially strained RuO₂, consistent with an altermagnetic metallic phase [1-3]. Additionally, we reveal a novel polar phase in strained films with significant implications for electrical transport—an unexpected treat in the realm of functional oxides. I will discuss these findings in detail, emphasizing their sensitivity to material defects and structure—key ingredients that are often overlooked but crucial in determining emergent quantum phenomena.

Reference:

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2. S. G. Jeong, S. Lee, B. Lin, Z. Yang, I. H. Choi, J. Y. Oh, S. Song, S. W. Lee, S. Nair, R. Choudhary, J. Parikh, S. Park, W. S. Choi, J. S. Lee, J. M. LeBeau, T. Low, and B. Jalan, **Metallicity and Anomalous Hall Effect in Epitaxially-Strained, Atomically-thin RuO₂ Films**, (2025) [[arxiv](#)]
3. S. G. Jeong, I. H. Choi, S. Lee, J. Y. Oh, S. Nair, J. H. Lee, C. Kim, A. Seo, W. S. Choi, T. Low, J. S. Lee, and B. Jalan, **Anisotropic Strain Relaxation-Induced Directional Ultrafast Carrier Dynamics in RuO₂ Films**, (2025) [[arxiv](#)]